

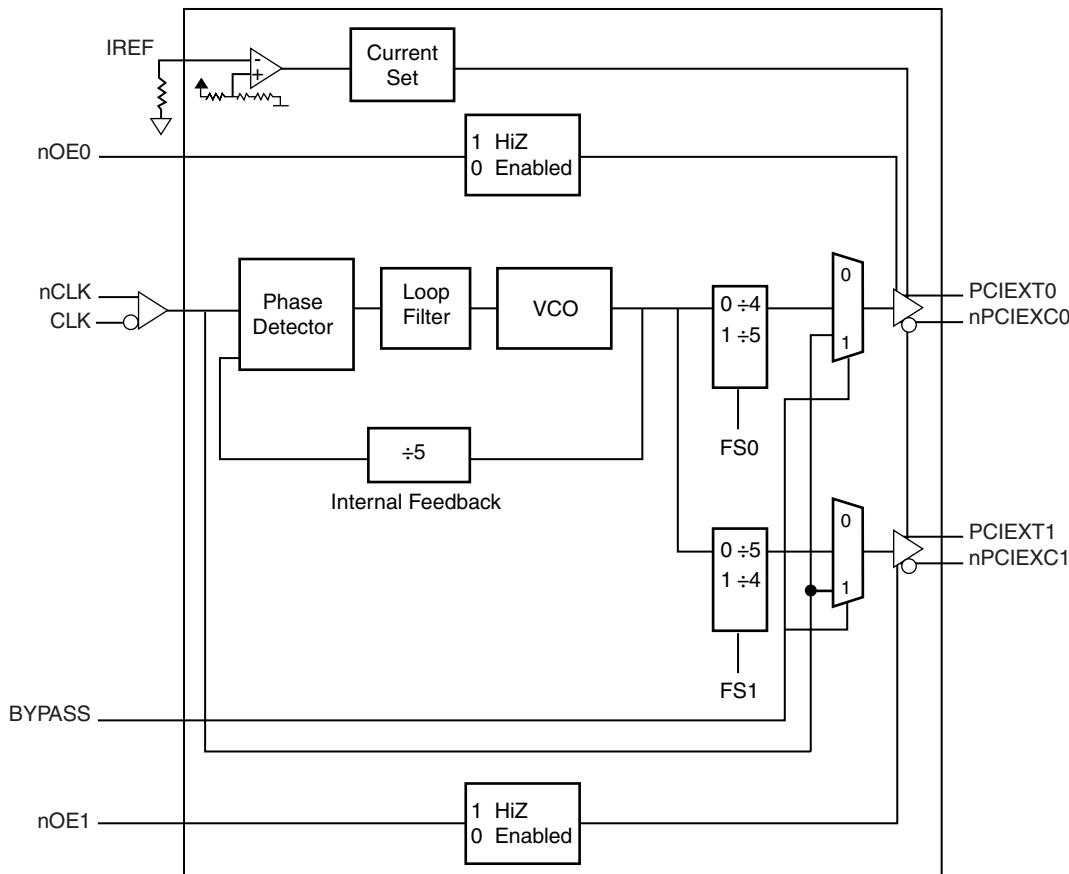
GENERAL DESCRIPTION



The ICS9DB202 is a high performance 1-to-2 Differential-to-HCSL Jitter Attenuator designed for use in PCI Express™ systems. In some PCI Express™ systems, such as those found in desktop PCs, the PCI Express™ clocks are generated from a low bandwidth, high phase noise PLL frequency synthesizer. In these systems, a jitter-attenuating device may be necessary in order to reduce high frequency random and deterministic jitter components from the PLL synthesizer and from the system board. The ICS9DB202 has two PLL bandwidth modes. In low bandwidth mode, the PLL loop bandwidth is 500kHz. This setting offers the best jitter attenuation and is still high enough to pass a triangular input spread spectrum profile. In high bandwidth mode, the PLL bandwidth is at 1MHz and allows the PLL to pass more spread spectrum modulation.

For serdes which have x10 reference multipliers instead of x12.5 multipliers, each of the two PCI Express™ outputs (PCIEXT0:1) can be set for 125MHz instead of 100MHz by configuring the appropriate frequency select pins (FS0:1).

BLOCK DIAGRAM



FEATURES

- Two 0.7V current mode differential HCSL output pairs
- One differential clock input
- CLK and nCLK supports the following input types: LVPECL, LVDS, L VHSTL, SSTL, HCSL
- Maximum output frequency: 140MHz
- Input frequency range: 90MHz - 140MHz
- VCO range: 450MHz - 700MHz
- Output skew: 110ps (maximum)
- Cycle-to-cycle jitter: 110ps (maximum)
- RMS phase jitter @ 100MHz, (1.5MHz - 22MHz): 2.42ps (typical)
- 3.3V operating supply
- 0°C to 70°C ambient operating temperature
- Available in both standard and lead-free RoHS compliant packages
- Industrial temperature information available upon request

PIN ASSIGNMENT

PLL_BW	1	VDDA
CLK	2	BYPASS
nCLK	3	IREF
FS0	4	FS1
VDD	5	VDD
GND	6	GND
PCIEXT0	7	PCIEXT1
PCIEXT0	8	PCIEXT1
VDD	9	VDD
nOE0	10	nOE1

ICS9DB202
20-Lead TSSOP
6.50mm x 4.40mm x 0.92
package body
G Package
Top View

ICS9DB202
20-Lead, 209-MIL SSOP
5.30mm x 7.20mm x 1.75mm
body package
F Package
Top View

TABLE 1. PIN DESCRIPTIONS

Number	Name	Type	Description
1	PLL_BW	Input	Pullup
2	CLK	Input	Pulldown
3	nCLK	Input	Pullup/ Pulldown
4	FS0	Input	Pullup
5, 9, 12, 16	V _{DD}	Power	
6, 15	GND	Power	
7, 8	PCIEXT0, PCIEXC0	Output	
10, 11	nOE0, nOE1	Input	Pulldown
13, 14	PCIEXC1, PCIEXT1	Output	
17	FS1	Input	Pulldown
18	IREF	Input	
19	BYPASS	Power	Pulldown
20	V _{DDA}	Power	

NOTE: *Pullup* and *Pulldown* refer to internal input resistors. See Table 2, Pin Characteristics, for typical values.

TABLE 2. PIN CHARACTERISTICS

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C _{IN}	Input Capacitance			4		pF
R _{PULLUP}	Input Pullup Resistor			51		kΩ
R _{PULLDOWN}	Input Pulldown Resistor			51		kΩ

TABLE 3A. RATIO OF OUTPUT FREQUENCY TO INPUT FREQUENCY FUNCTION TABLE, FS0

Inputs	Outputs
FS0	PCIEX0
0	5/4
1	1

TABLE 3B. RATIO OF OUTPUT FREQUENCY TO INPUT FREQUENCY FUNCTION TABLE, FS1

Inputs	Outputs
FS1	PCIEX1
0	1
1	5/4

TABLE 3C. BYPASS TABLE

Inputs	Mode
	BYPASS
0	PLL Mode
1	Bypass Mode (output = inputs)

TABLE 3D. OUTPUT ENABLE FUNCTION TABLE, NOE0

Inputs	Outputs
nOE0	PCIEX0
0	Enabled
1	HiZ

TABLE 3E. OUTPUT ENABLE FUNCTION TABLE, NOE1

Inputs	Outputs
nOE1	PCIEX1
0	Enabled
1	HiZ

TABLE 3F. PLL BANDWIDTH TABLE

Inputs	Bandwidth
	PLL_BW
0	500kHz
1	1MHz

ABSOLUTE MAXIMUM RATINGS

Supply Voltage, V_{DD}	4.6V
Inputs, V_I	-0.5V to $V_{DD} + 0.5$ V
Outputs, V_O	-0.5V to $V_{DD} + 0.5$ V
Package Thermal Impedance, θ_{JA}	
20 Lead TSSOP	73.2°C/W (0 Ifpm)
20 Lead SSOP	80.8°C/W (0 Ifpm)
Storage Temperature, T_{STG}	-65°C to 150°C

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

TABLE 4A. POWER SUPPLY DC CHARACTERISTICS, $V_{DD} = V_{DDA} = 3.3V \pm 5\%$, $T_A = 0^\circ C$ TO $70^\circ C$, $R_{REF} = 475\Omega$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Core Supply Voltage		3.135	3.3	3.465	V
V_{DDA}	Analog Supply Voltage		3.135	3.3	3.465	V
I_{DD}	Power Supply Current				112	mA
I_{DDA}	Analog Supply Current				22	mA

TABLE 4B. LVCMOS / LVTTL DC CHARACTERISTICS, $V_{DD} = V_{DDA} = 3.3V \pm 5\%$, $T_A = 0^\circ C$ TO $70^\circ C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{IH}	Input High Voltage		2		$V_{DD} + 0.3$	mV
V_{IL}	Input Low Voltage		-0.3		0.8	mV
I_{IH}	Input High Current nOE0, nOE1, FS1 FS0, PLL_BW	$V_{DD} = V_{IN} = 3.465V$			150	μA
					5	
I_{IL}	Input Low Current nOE0, nOE1, FS1 FS0, PLL_BW	$V_{DD} = 3.465V, V_{IN} = 0V$	-5			μA
			-150			

TABLE 4C. DIFFERENTIAL DC CHARACTERISTICS, $V_{DD} = V_{DDA} = 3.3V \pm 5\%$, $T_A = 0^\circ C$ TO $70^\circ C$, $R_{REF} = 475\Omega$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
I_{IH}	Input High Current	$V_{DD} = V_{IN} = 3.465V$			150	μA
I_{IL}	Input Low Current	$V_{DD} = 3.465V, V_{IN} = 0V$			150	μA
V_{PP}	Peak-to-Peak Input Voltage		0.15		1.3	V
V_{CMR}	Common Mode Input Voltage; NOTE 1, 2		GND + 0.5		$V_{DD} - 0.85$	V

NOTE 1: Common mode voltage is defined as V_{IH} .

NOTE 2: For single ended applications, the maximum input voltage for CLK, nCLK is $V_{DD} + 0.3V$.

TABLE 4D. HCSL DC CHARACTERISTICS, $V_{DD} = V_{DDA} = 3.3V \pm 5\%$, $T_A = 0^\circ C$ TO $70^\circ C$, $RREF = 475\Omega$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
I_{OH}	Output Current		12	14	16	mA
V_{OH}	Output High Voltage		610		780	mV
V_{OL}	Output Low Voltage				65	mV
I_{OZ}	High Impedance Leakage Current		-10		10	μA
V_{OX}	Output Crossover Voltage		250		550	mV

TABLE 5. AC CHARACTERISTICS, $V_{DD} = V_{DDA} = 3.3V \pm 5\%$, $T_A = 0^\circ C$ TO $70^\circ C$, $RREF = 475\Omega$

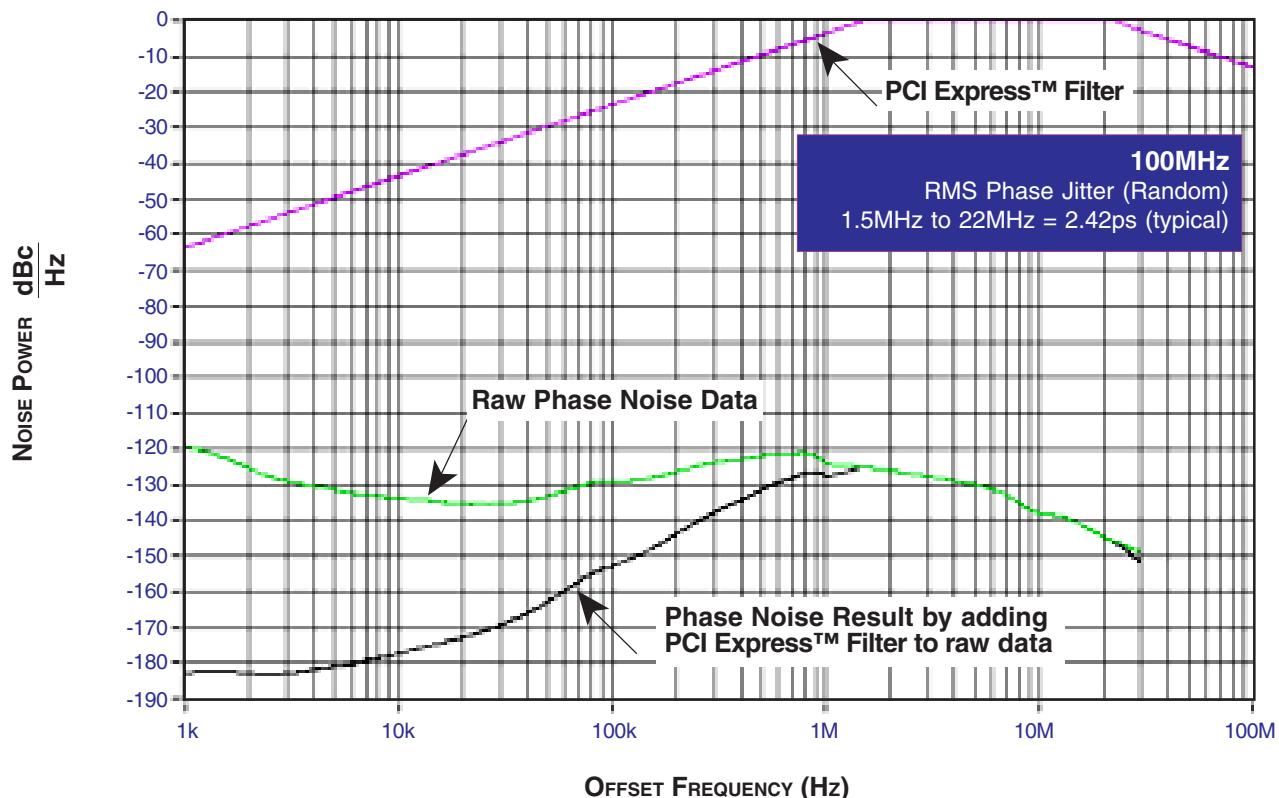
Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{MAX}	Output Frequency				140	MHz
$t_{sk(o)}$	Output Skew; NOTE 1, 2			50	110	ps
$t_{jit(cc)}$	Cycle-to-Cycle Jitter	Outputs @ Different Frequencies			110	ps
		Outputs @ Same Frequencies			50	ps
$t_{jit(\emptyset)}$	RMS Phase Jitter (Random); NOTE 3	Integration Range: 1.5MHz - 22MHz		2.42		ps
t_R / t_F	Output Rise/Fall Time	20% to 80%	300		1100	ps
odc	Output Duty Cycle		48		52	%

NOTE 1: Defined as skew between outputs at the same supply voltage and with equal load conditions.
Measured at the output differential cross points.

NOTE 2: This parameter is defined in accordance with JEDEC Standard 65.

NOTE 3: Please refer to the Phase Noise Plot following this section.

TYPICAL PHASE NOISE AT 100MHz

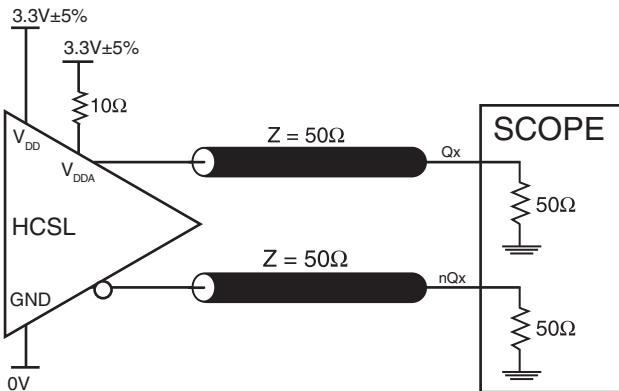


The illustrated phase noise plot was taken using a low phase noise signal generator, the noise floor of the signal generator is less than that of the device under test.

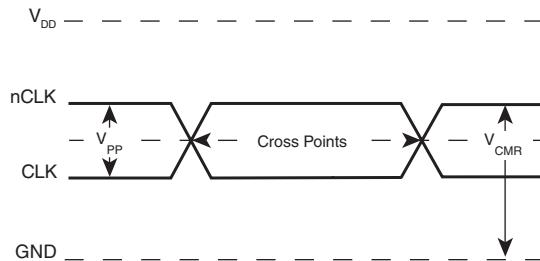
Using this configuration allows one to see the true spectral purity or phase noise performance of the PLL in the device under test.

Due to the tracking ability of a PLL, it will track the input signal up to its loop bandwidth. Therefore, if the input phase noise is greater than that of the PLL, it will increase the output phase noise performance of the device. It is recommended that the phase noise performance of the input is verified in order to achieve the above phase noise performance.

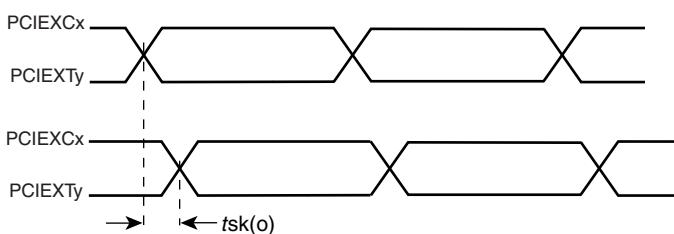
PARAMETER MEASUREMENT INFORMATION



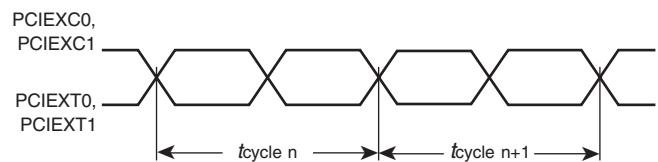
3.3V HCSL OUTPUT LOAD AC TEST CIRCUIT



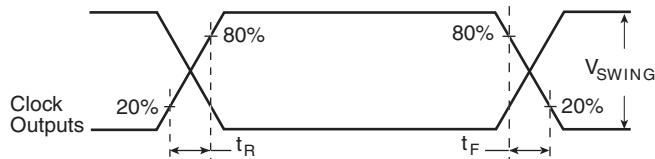
DIFFERENTIAL INPUT LEVEL



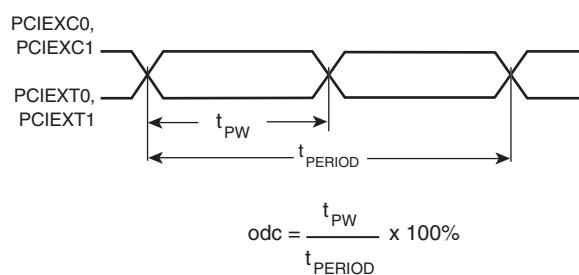
OUTPUT SKEW



CYCLE-TO-CYCLE JITTER



HCSL OUTPUT RISE/FALL TIME



OUTPUT DUTY CYCLE/PULSE WIDTH/PERIOD

APPLICATION INFORMATION

POWER SUPPLY FILTERING TECHNIQUES

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. The ICS9DB202 provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL. V_{DD} and V_{DDA} should be individually connected to the power supply plane through vias, and bypass capacitors should be used for each pin. To achieve optimum jitter performance, power supply isolation is required. *Figure 1* illustrates how a 24Ω resistor along with a $10\mu F$ and a $.01\mu F$ bypass capacitor should be connected to each V_{DDA} pin. The 10Ω resistor can also be replaced by a ferrite bead.

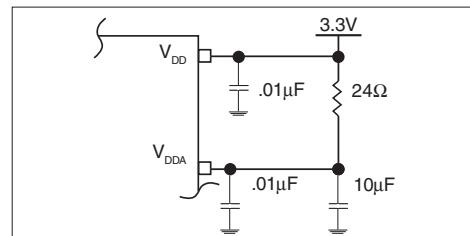


FIGURE 1. POWER SUPPLY FILTERING

WIRING THE DIFFERENTIAL INPUT TO ACCEPT SINGLE ENDED LEVELS

Figure 2 shows how the differential input can be wired to accept single ended levels. The reference voltage $V_{REF} = V_{DD}/2$ is generated by the bias resistors R1, R2 and C1. This bias circuit should be located as close as possible to the input pin. The ratio

of R1 and R2 might need to be adjusted to position the V_{REF} in the center of the input voltage swing. For example, if the input clock swing is only 2.5V and $V_{DD} = 3.3V$, V_{REF} should be 1.25V and $R2/R1 = 0.609$.

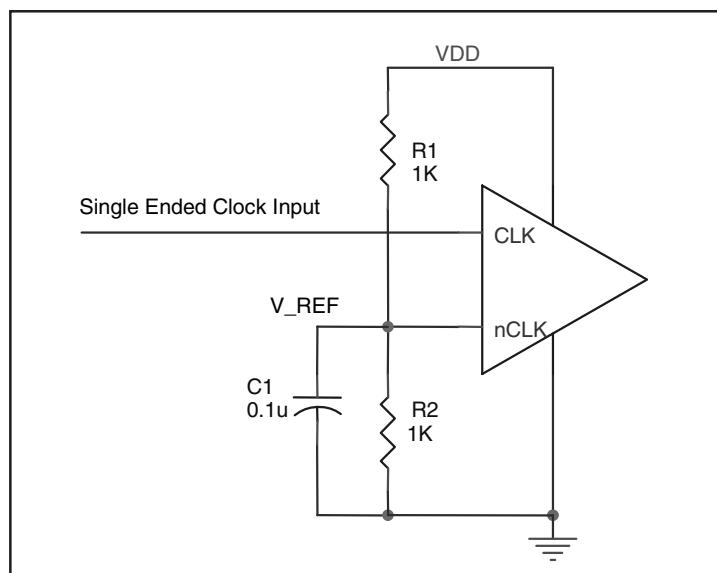


FIGURE 2. SINGLE ENDED SIGNAL DRIVING DIFFERENTIAL INPUT

DIFFERENTIAL CLOCK INPUT INTERFACE

The CLK /nCLK accepts LVDS, LVPECL, LVHSTL, SSTL, HCSL and other differential signals. Both V_{SWING} and V_{OH} must meet the V_{PP} and V_{CMR} input requirements. Figures 3A to 3D show interface examples for the HiPerClockS CLK/nCLK input driven by the most common driver types. The input interfaces suggested here are

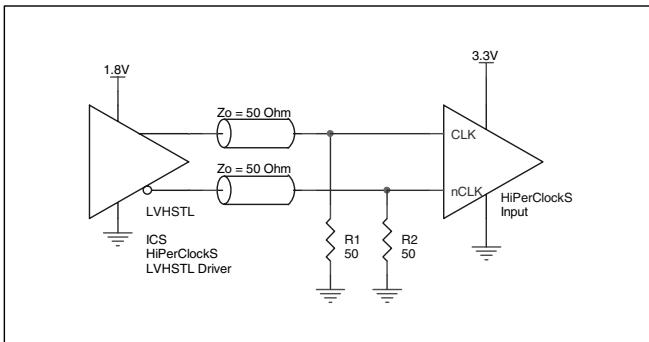


FIGURE 3A. HiPerClockS CLK/nCLK Input Interface Driven by ICS HiPerClockS LVHSTL Driver

examples only. Please consult with the vendor of the driver component to confirm the driver termination requirements. For example in *Figure 3A*, the input termination applies for ICS HiPerClockS LVHSTL drivers. If you are using an LVHSTL driver from another vendor, use their termination recommendation.

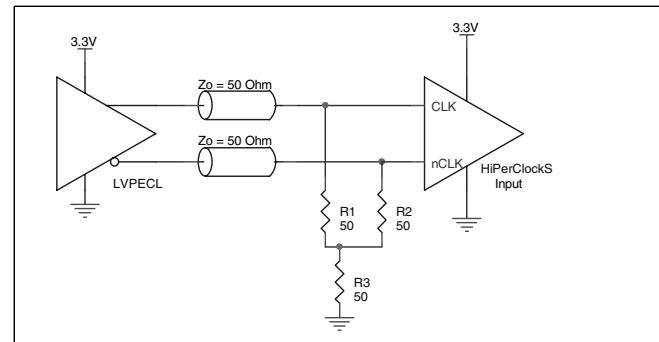


FIGURE 3B. HiPerClockS CLK/nCLK Input Interface Driven by 3.3V LVPECL Driver

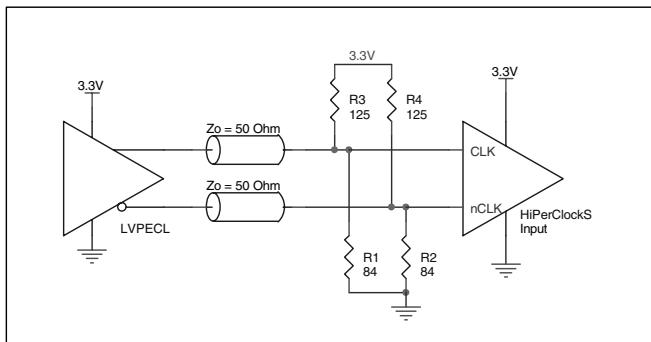


FIGURE 3C. HiPerClockS CLK/nCLK Input Interface Driven by 3.3V LVPECL Driver

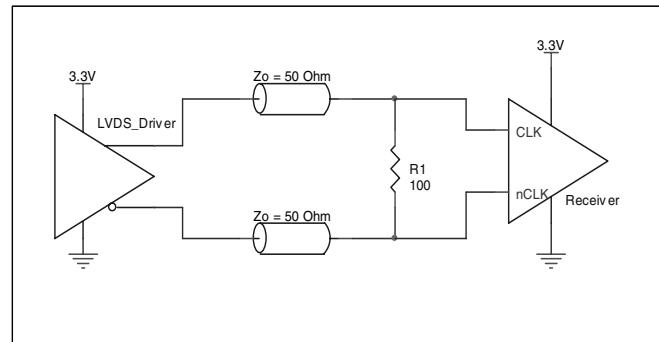


FIGURE 3D. HiPerClockS CLK/nCLK Input Interface Driven by 3.3V LVDS Driver

RECOMMENDATIONS FOR UNUSED INPUT AND OUTPUT PINS

INPUTS:

LVC MOS CONTROL PINS:

All control pins have internal pull-ups or pull-downs; additional resistance is not required but can be added for additional protection. A 1kW resistor can be used.

OUTPUTS:

HCSL OUTPUT

All unused HCSL outputs can be left floating. We recommend that there is no trace attached. Both sides of the differential output pair should either be left floating or terminated.

RELIABILITY INFORMATION

TABLE 6A. θ_{JA} VS. AIR FLOW TABLE FOR 20 LEAD TSSOP PACKAGE

θ_{JA} by Velocity (Linear Feet per Minute)

	0	200	500
Single-Layer PCB, JEDEC Standard Test Boards	114.5°C/W	98°C/W	88°C/W
Multi-Layer PCB, JEDEC Standard Test Boards	73.2°C/W	66.6°C/W	63.5°C/W

NOTE: Most modern PCB designs use multi-layered boards. The data in the second row pertains to most designs.

TABLE 6B. θ_{JA} VS. AIR FLOW TABLE FOR 20 LEAD SSOP PACKAGE

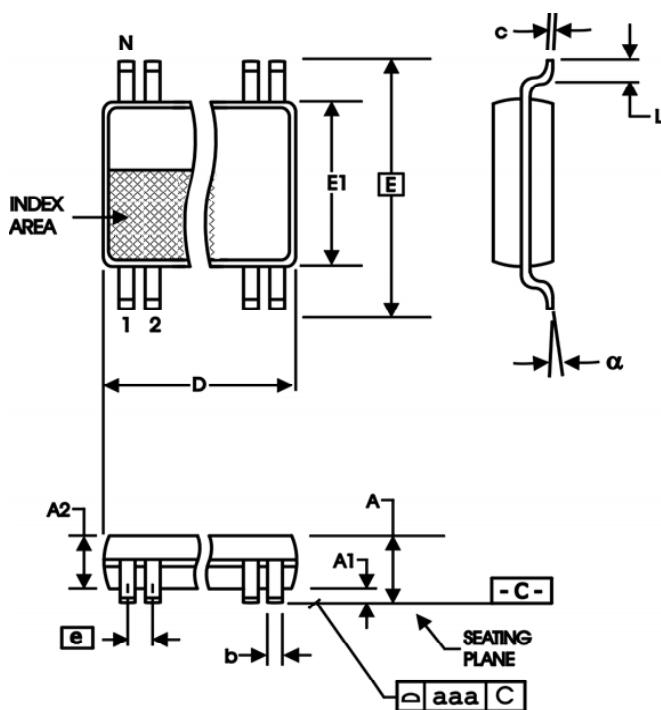
θ_{JA} by Velocity (Linear Feet per Minute)

	0	200	500
Multi-Layer PCB, JEDEC Standard Test Boards	80.8°C/W	73.2°C/W	69.2°C/W

TRANSISTOR COUNT

The transistor count for ICS9DB202 is: 2471

PACKAGE OUTLINE - G SUFFIX FOR 20 LEAD TSSOP



PACKAGE OUTLINE - F SUFFIX FOR 20 LEAD SSOP

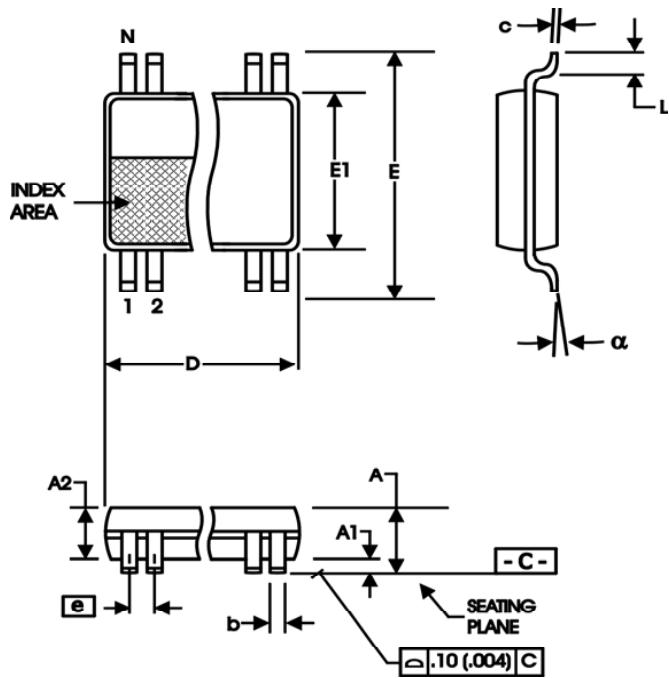


TABLE 6A. PACKAGE DIMENSIONS

SYMBOL	Millimeters	
	Minimum	Maximum
N	20	
A	--	1.20
A1	0.05	0.15
A2	0.80	1.05
b	0.19	0.30
c	0.09	0.20
D	6.40	6.60
E	6.40 BASIC	
E1	4.30	4.50
e	0.65 BASIC	
L	0.45	0.75
α	0°	8°
aaa	--	0.10

Reference Document: JEDEC Publication 95, MO-153

TABLE 6B. PACKAGE DIMENSIONS

SYMBOL	Millimeters	
	Minimum	Maximum
N	20	
A	--	2.0
A1	0.05	--
A2	1.65	1.85
b	0.22	0.38
c	0.09	0.25
D	6.90	7.50
E	7.40	8.20
E1	5.0	5.60
e	0.65 BASIC	
L	0.55	0.95
α	0°	8°

Reference Document: JEDEC Publication 95, MO-150

TABLE 7. ORDERING INFORMATION

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
ICS9DB202CG	ICS9DB202CG	20 Lead TSSOP	Tube	0°C to 70°C
ICS9DB202CGT	ICS9DB202CG	20 Lead TSSOP	2500 Tape & Reel	0°C to 70°C
ICS9DB202CGLF	ICS9DB202CGL	20 Lead "Lead-Free" TSSOP	Tube	0°C to 70°C
ICS9DB202CGLFT	ICS9DB202CGL	20 Lead "Lead-Free" TSSOP	2500 Tape & Reel	0°C to 70°C
ICS9DB202CF	ICS9DB202CF	20 Lead SSOP	Tube	0°C to 70°C
ICS9DB202CFT	ICS9DB202CF	20 Lead SSOP	1000 Tape & Reel	0°C to 70°C
ICS9DB202CFLF	ICS9DB202CFLF	20 Lead "Lead-Free" SSOP	Tube	0°C to 70°C
ICS9DB202CFLFT	ICS9DB202CFLF	20 Lead "Lead-Free" SSOP	1000 Tape & Reel	0°C to 70°C

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

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REVISION HISTORY SHEET

Rev	Table	Page	Description of Change	Date
B	T4D	4	HCSL Table -adjusted V_{OH} min from 680mV to 610mV and added V_{OH} max.	12/21/04
B	T7	6	Updated HCSL Output Load AC Test Circuit Diagram.	
		8	Application Information - added <i>Recommendations for Unused Input and Output Pins.</i>	3/8/06
B	T4D	4	HCSL DC Characteristics - corrected units for V_{OH} & V_{OL} from V to mV.	5/26/06
B		1	Feature Section - added Input Frequency Range and VCO Range.	7/14/06

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For Sales

800-345-7015
408-284-8200
Fax: 408-284-2775

For Tech Support

netcom@idt.com
480-763-2056

Corporate Headquarters

Integrated Device Technology, Inc.
6024 Silver Creek Valley Road
San Jose, CA 95138
United States
800 345 7015
+408 284 8200 (outside U.S.)

Asia Pacific and Japan

Integrated Device Technology
Singapore (1997) Pte. Ltd.
Reg. No. 199707558G
435 Orchard Road
#20-03 Wisma Atria
Singapore 238877
+65 6 887 5505

Europe

IDT Europe, Limited
321 Kingston Road
Leatherhead, Surrey
KT22 7TU
England
+44 (0) 1372 363 339
Fax: +44 (0) 1372 378851

